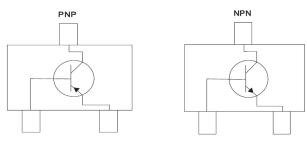


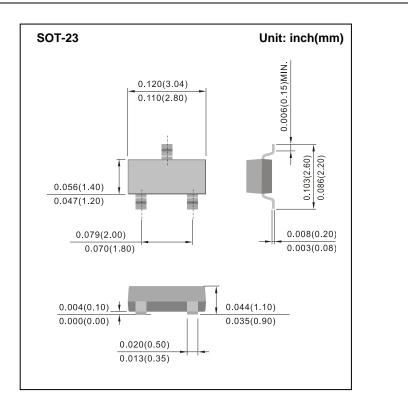
- NPN and PNP silicon, planar design
- Collector current  $I_C = 500 \text{mA}$
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std..

#### (Halogen Free)

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams





#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	MMBTA05-AU	MMBTA55-AU	MMBTA06-AU	MMBTA56-AU	UNITS
Marking		B05	B55	B06	B56	
Collector-Emitter Voltage	V <sub>CEO</sub>	60		80		V
Collector-Base Voltage	V <sub>CEO</sub>	60		80		V
Emitter-Base Voltage	V <sub>EBO</sub>	4			V	
Collector Current-Continuous	Ι <sub>C</sub>	500			mA	
Circuit Figure		NPN	PNP	NPN	PNP	

#### **Maximum Ratings and Thermal Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

CHARACTERISTIC	SYMBOL	MAX.	UNITS
Total device dissipation FR-4 board (Note 1) $T_A=25^{\circ}C$	P	225	mW
derate above 25°C	P <sub>D</sub>	1.8	mW/°C
Typical thermal resistance	$R_{ extsf{ heta}JA}$	556	°C/W
Total device dissipation alumina substrate (Note 2) $T_A=25^{\circ}C$	5	300	mW
derate above 25°C	P <sub>D</sub>	2.4	mW/°C
Typical thermal resistance	$R_{ ext{ hetaJA}}$	417	°C/W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C

Note : 1. FR-4=70 x 60 x 1mm.

2. Alumina=0.4 x 0.3 x 0.024 in. 99.5 alumina.



### **Electrical Characteristics** ( $T_A=25^{\circ}C$ unless otherwise noted)

PARAM	IETER	SYMBOL	MIN.	MAX.	UNITS
OFF Characteristics			· · ·		·
Collector-Emitter Breakdown Voltage	)				
(I <sub>C</sub> =1.0mA, I <sub>B</sub> =0)	MMBTA05-AU, MMBTA55-AU	$V_{(BR)CEO}$	60	-	V
	MMBAT06-AU, MMBTA56-AU		80	-	
Emitter-Base Breakdown Voltage			4		V
(I <sub>E</sub> =100μA, I <sub>C</sub> =0)		$V_{(BR)EBO}$	4	-	V
Collector Cutoff Current			-	0.1	
(V <sub>CE</sub> =60V, I <sub>B</sub> =0)		I <sub>CES</sub>			μΑ
Collector Cutoff Current					
(V <sub>CB</sub> =60V, I <sub>E</sub> =0)	MMBTA05-AU, MMBTA55-AU	I <sub>CBO</sub>	-	0.1	μΑ
(V <sub>CB</sub> =80V, I <sub>E</sub> =0)	MMBAT06-AU, MMBTA56-AU		-	0.1	
ON characteristics			1		
DC Current Gain					
$(I_C=10mA, V_{CE}=1V)$		f <sub>FE</sub>	100	-	-
(I <sub>C</sub> =100mA, V <sub>CE</sub> =1V)			100	-	
Collector-Emitter Saturation Voltage		M			
(I <sub>C</sub> =100mA, I <sub>B</sub> =10mA)		$V_{CE(SAT)}$	-	0.25	V
Base-Emitter On Voltage		V			
(I <sub>C</sub> =100mA, V <sub>CE</sub> =1V)		$V_{BE(ON)}$	-	1.2	V
Small-signal characteristics			· · · · · · · · · · · · · · · · · · ·		
Current-Gain-Bandwidth Product		f	100	-	MHz
(I <sub>C</sub> =10mA, V <sub>CE</sub> =2V, f=100MHz)		f <sub>T</sub>			IVITIZ

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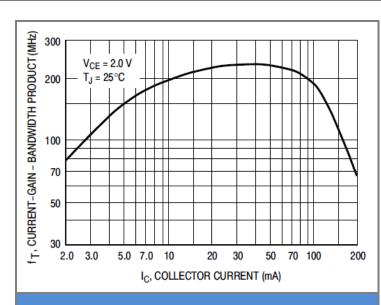
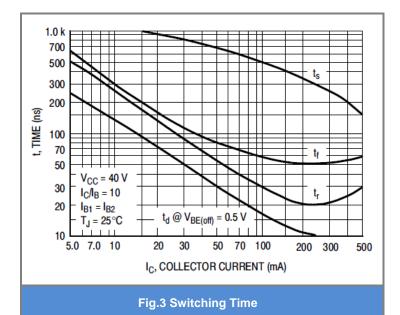
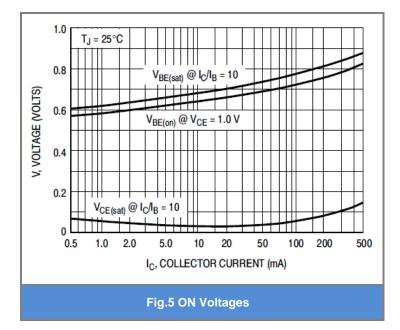


Fig.1 Current-Gain—Bandwidth Product





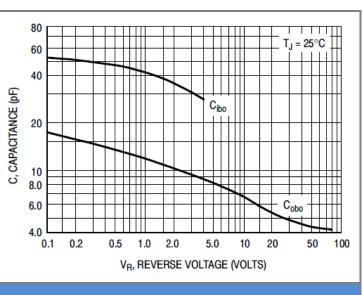
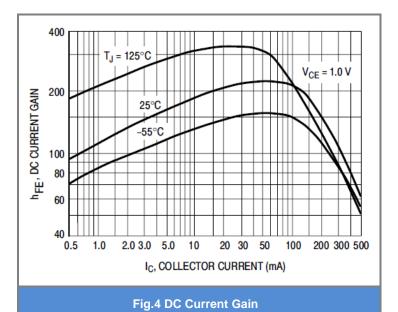
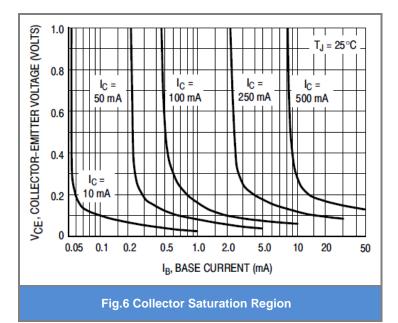


Fig.2 Capacitance





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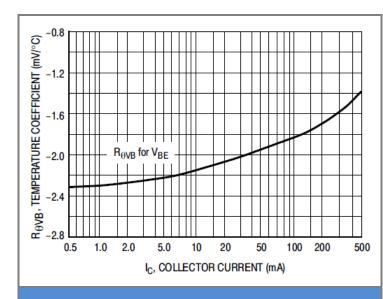


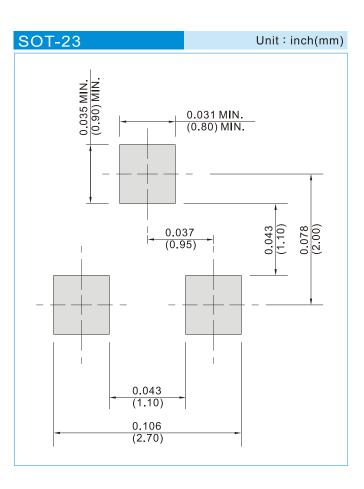
Fig.7 Base-Emitter Temperature Coefficient



### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
MMBTA05-AU_R1_000A1	SOT-23	3K / 7" Reel	B05	Halogen Free
MMBTA05-AU_R2_000A1	SOT-23	12K / 13" Reel	B05	Halogen Free

#### **Mounting Pad Layout**





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